Docket No. N1085-00040
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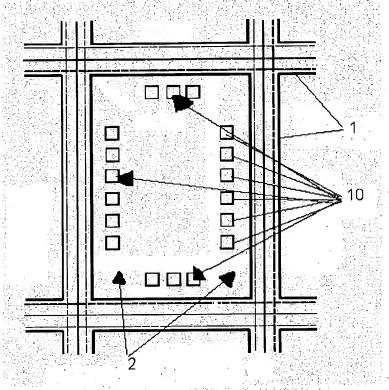


FIG. 1

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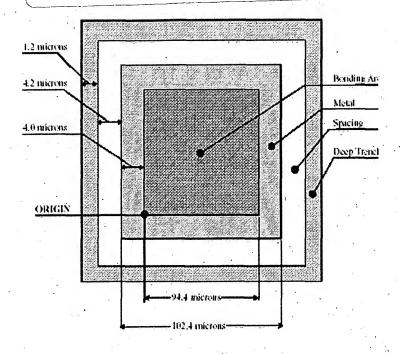


FIG. 2a

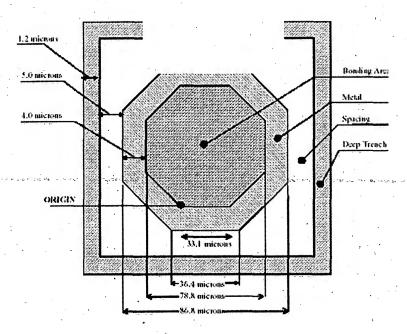


FIG. 2b

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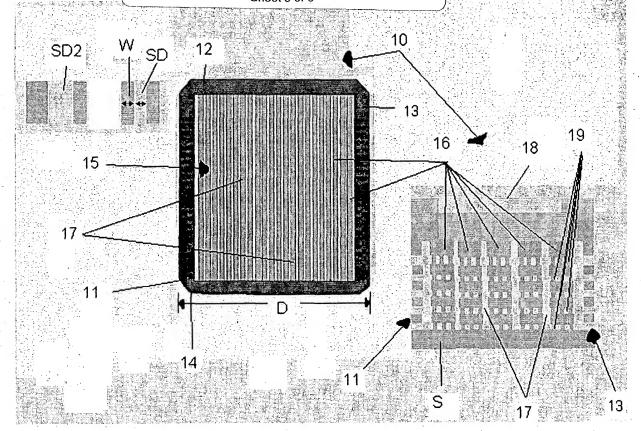


FIG. 3a FIG. 3b

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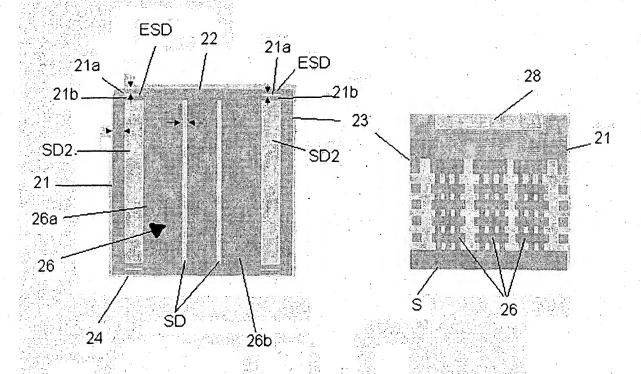


FIG. 4b

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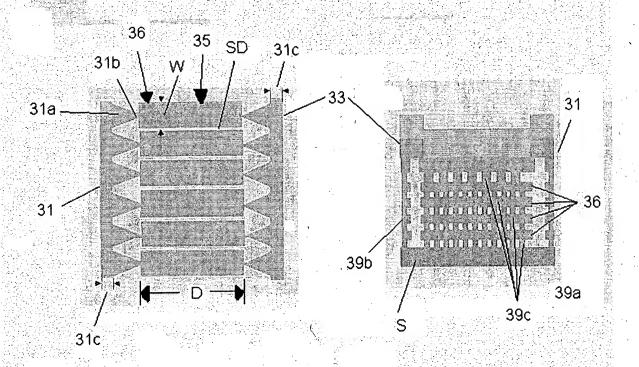
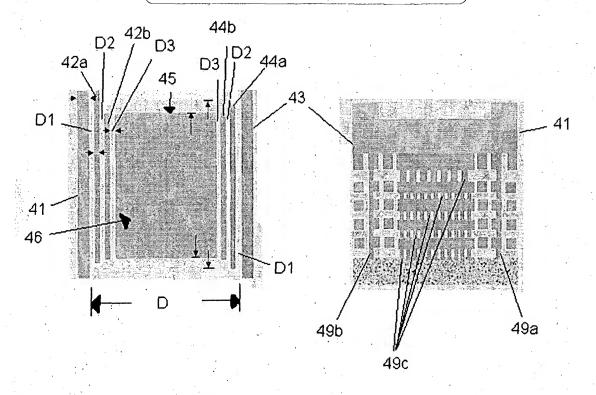


FIG. 5a

FIG. 5b

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FļG. 6a

FIG. 6b